

IXFH26N60Q Datasheet



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DiGi Electronics Part Number IXFH26N60Q-DG

Manufacturer IXYS

Manufacturer Product Number IXFH26N60Q

Description MOSFET N-CH 600V 26A TO247AD

Detailed Description N-Channel 600 V 26A (Tc) 360W (Tc) Through Hole

TO-247AD (IXFH)



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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
IXFH26N60Q	IXYS
Series:	Product Status:
HiPerFET™	Obsolete
FET Type:	Technology:
N-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
600 V	26A (Tc)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ ld, Vgs:
10V	250mOhm @ 13A, 10V
Vgs(th) (Max) @ Id:	Gate Charge (Qg) (Max) @ Vgs:
4.5V @ 4mA	200 nC @ 10 V
Vgs (Max):	Input Capacitance (Ciss) (Max) @ Vds:
±20V	5100 pF @ 25 V
FET Feature:	Power Dissipation (Max):
	360W (Tc)
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Through Hole
Supplier Device Package:	Package / Case:
TO-247AD (IXFH)	TO-247-3
Base Product Number:	
IXFH26	

Environmental & Export classification

Moisture Sensitivity Level (MSL):	ECCN:
Not Applicable	EAR99
HTSUS:	
8541.29.0095	



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